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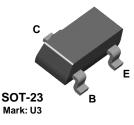
Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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BSS64



BSS64



NPN General Purpose Amplifier

This device is designed for general purpose high voltage amplifiers and gas discharge display driving. Sourced from Process 16.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	120	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах	Units
		*BSS64	
PD	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

*Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

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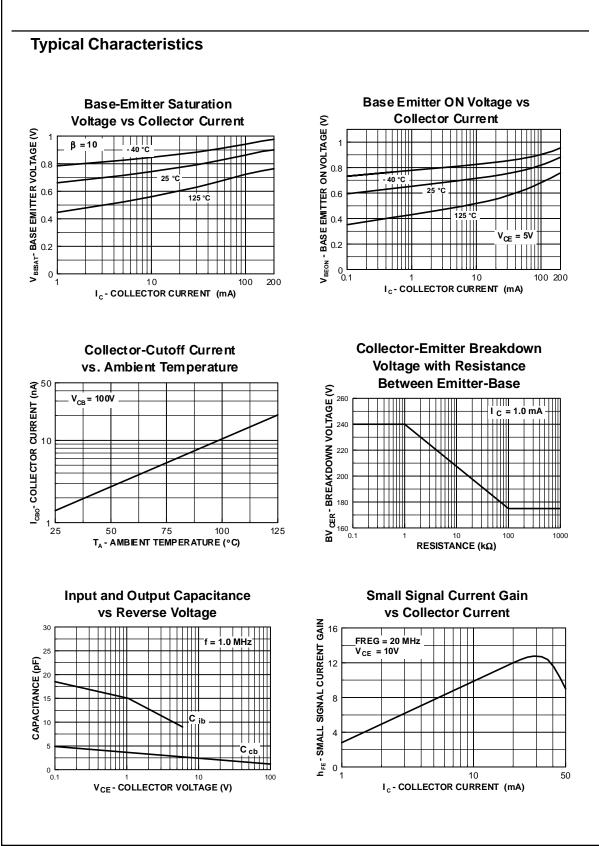
NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 4.0 \text{ mA}, I_{\rm B} = 0$	80		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	120		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \mu {\rm A}, I_{\rm C} = 0$	5.0		V
Сво	Collector-Cutoff Current	$V_{CB} = 90 \text{ V}, \text{ I}_{E} = 0$		0.1	μA
1		$V_{CB} = 90 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 150^{\circ}\text{C}$ $V_{EB} = 5.0 \text{ V}, \text{ I}_{C} = 0$		50	μA
EBO	Emitter-Cutoff Current	$v_{EB} = 5.0 v, I_C = 0$		200	nA
ON CHAR	ACTERISTICS				
h _{FE}	DC Current Gain	I_{C} = 10 mA, V_{CE} = 1.0 V	20		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 4.0 \text{ mA}, I_{B} = 400 \mu\text{A}$		0.15	V
	Base-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 15 \text{ mA}$ $I_{\rm C} = 4.0 \text{ mA}, I_{\rm B} = 400 \mu \text{A}$		0.2	V
V _{BE(sat)}	Dase Emilier Galdrailon Voltage	ις – 4.0 ma, iβ = 400 μA		1.2	v
	GNAL CHARACTERISTICS				
	Current Gain - Bandwidth Product	I _C = 4.0 mA, V _{CE} = 10,	60		MHz
F		$1_{\rm C} - 4.0$ $1_{\rm L}$, $v_{\rm CE} = 10$,	00		
f _T		f = 35 MHz			
C _{ob} Spice NPN (Is=2 Ikr=0 Rc=	Output Capacitance Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V _{CB} = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2			
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V _{CB} = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2		=3.197 Nc=	=2 lsc=0
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 21 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10) Al Characteristics Typical Pulsed Current Gain	V _{CB} = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2 5 Cje=18.79p Mje=.3416 Vje=.75 Collector-E	5 Tr=1.202	=3.197 Nc= n Tf=560p	-2 lsc=0 ltf=50m
Cob Spice NPN (Is=2 Ikr=0 Rc= Vtf=5 Xtf	Model 2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 =1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc= =8 Rb=10)	V _{CB} = 10 V, f = 1.0 MHz 5 Ne=1.249 Ise=2.511f Ikf=.3458 2 5 Cje=18.79p Mje=.3416 Vje=.75 Collector-E	5 Tr=1.202	=3.197 Nc= n Tf=560p	-2 lsc=0 ltf=50m
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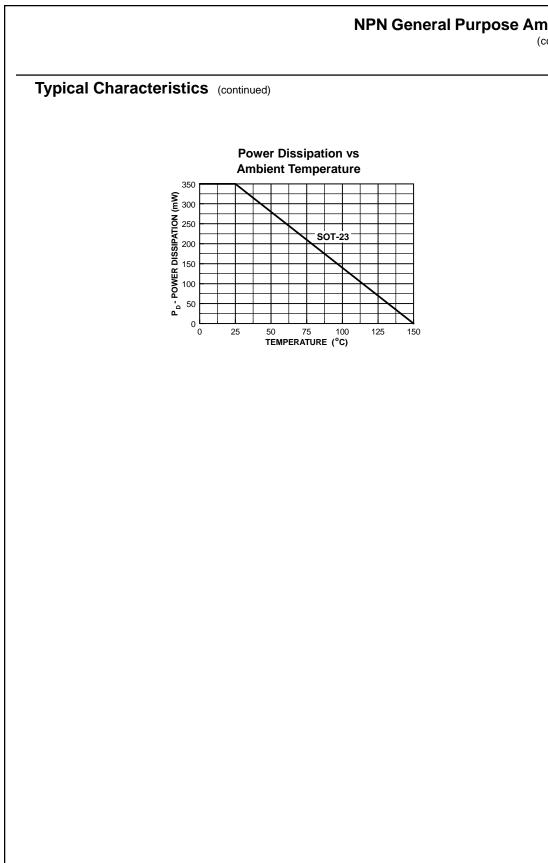
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NPN General Purpose Amplifier (continued)



NPN General Purpose Amplifier (continued)



BSS64

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